

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error Rows
1	BRS	L1	25	indium adj doped adj2 (silicon or poly or polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:39			0
2	BRS	L2	0	(in-situ or insitu or (in adj situ)) with (CVD or (chemical adj vapor adj deposit\$5)) with (silicon or polysilicon or poly\$1) with indium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:31			0
3	BRS	L3	10	(in-situ or insitu or (in adj situ)) with (silicon or polysilicon or poly\$1) with indium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 11:54			0
4	BRS	L4	272	(in-situ or insitu or (in adj situ)) with (CVD or (chemical adj vapor adj deposit\$5)) with (silicon or polysilicon or poly\$1) with (indium or In or "In")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:03			0
5	BRS	L5	93280	indium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 11:59			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error Count
6	BRS	L6	17	4 and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 11:59			0
7	BRS	L7	481	(in-situ or insitu or (in adj situ)) with (CVD or chemical adj vapor adj deposit\$5)) with (indium or In or "In")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:03			0
8	BRS	L8	24	7 and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:04			0
9	BRS	L9	7	8 not 6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:04			0
10	BRS	L10	969	indium adj (chloride\$1 or trichloride\$1 or tri-chloride\$1 or (tri adj chloride\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:41			0
11	BRS	L11	968	InCl3 or "InCl3" or "InCl.sub.3" or "In Cl.sub.3"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:42			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error
12	BRS	L12	1776	10 or 11	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:42			0
13	BRS	L13	2	(in-situ or insitu or (in adj situ)) with 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:44			0
14	BRS	L14	2913 5	(implant\$8 or dop\$4 or inject\$4 or introduc\$4) with (indium or In or "In") with (silicon or poly\$1 or polysilicon\$1 or poly-silicon\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:46			0
15	BRS	L15	4670	14 and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:46			0
16	BRS	L16	149	15 and 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:47			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error Count
17	BRS	L178		14 same 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:48			0
18	BRS	L180		(in-situ or insitu or (in adj situ)) same (silicon or polysilicon or poly\$1 or poly-silicon) same 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:56			0
19	BRS	L1964		(in-situ or insitu or (in adj situ)) and (silicon or polysilicon or poly\$1 or poly-silicon) and 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:42			0
20	IS&R	L201		("20040000695").PN.	USPAT; US-PGPUB	2004/10/07 13:42			0
21	BRS	L213		16 and (in-situ or insitu or (in adj situ))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:56			0